High-Speed Current Amplifier



Features	 Bandwidth and Frequency Response Independent of Detector Capacitance (up to 50 pF) Low Noise 3.5 pA/√Hz Equivalent Input Noise Current Bandwidth DC 20 MHz Transimpedance (Gain) 1 x 10⁵ V/A Protection against ± 3.5 kV Transients 	
Applications	 Photodiode and Photomultiplier Amplifier Spectroscopy Charge Amplifier Ionisation Detectors Preamplifier for Lock-Ins, A/D Converters, etc. 	
Specifications	Test Conditions	$Vs = \pm 15 \text{ V}, Ta = 25^{\circ}\text{C}$
Gain	Transimpedance Gain Accuracy	1 x 10 5 V/A (@ 50 Ω load) \pm 1 %
Frequency Response	Lower Cut-Off Frequency Upper Cut-Off Frequency (- 3 dB) Rise / Fall Time (10 % - 90 %) Gain Flatness	DC 20 MHz 18 ns ± 0.3 dB
Input	Equ. Input Noise Current Equ. Input Noise Voltage Input Bias Current Input Bias Current Drift Offset Current Compensation Input Current Range Input Offset Voltage DC Input Impedance	$3.5 \text{ pAV} \sqrt{\text{Hz}}$ (@ 100 kHz) $0.8 \text{ nV} / \sqrt{\text{Hz}}$ (@ 100 kHz) $18 \mu\text{A}$ typ. 0.8 nA / K $\pm 20 \mu\text{A}$ adjustable by offset trimpot $\pm 15 \mu\text{A}$ (for linear amplification) 3 mV 50Ω (virtual) // 5 pF
Output	Output Voltage Range Output Impedance	\pm 1.5 V (@ 50 Ω load) for linear operation and low harmonic distortion 50 Ω (terminate with 50 Ω load for best performance)
Bias Output	Bias Output Voltage Range Bias Output Impedance	\pm 12 V, adjustable by bias trimpot 10 kΩ // 1 μF

SOPHISTICATED TOOLS FOR SIGNAL RECOVERY

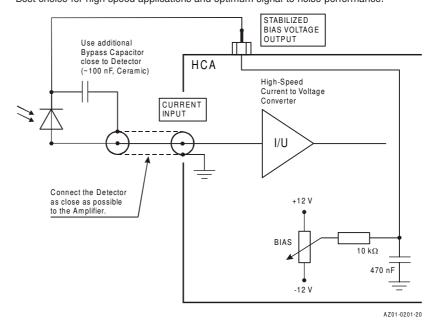
F E M T O

High-Speed Current Amplifier

Specifications (continued) Power Supply	Supply Voltage Supply Current	\pm 15 V \pm 70 mA typ. (depends on operating conditions, recommended power supply capability minimum \pm 150 mA)
Case	Weight Material	210 g (0.5 lbs) AlMg4.5Mn, nickel-plated
Temperature Range	Storage Temperature Operating Temperature	-40 +100 °C 0 +60 °C
Absolute Maximum Ratings	Input Voltage Input Voltage Transient Power Supply Voltage	±5 V ±3.5 kV (pulsewidth 10 ns) ±22 V
Connectors	Input Output Power Supply	BNC LEMO series 1S, 3-pin fixed socket Pin 1: + 15V Pin 2: - 15V Pin 3: GND PIN 2 PIN 2 PIN 3 GND

Application Diagrams

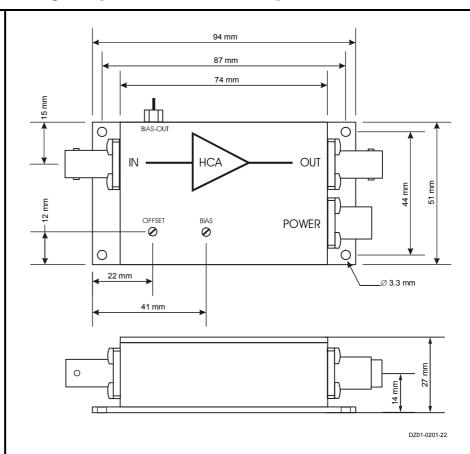
Photo Detector Biasing in Photoconductive Mode: Best choice for high speed applications and optimum signal to noise performance.



F E M T O

High-Speed Current Amplifier

Dimensions



FEMTO Messtechnik GmbH Klosterstr. 64 10179 Berlin · Germany Phone: +49 30 280 4711-0 Fax: +49 30 280 4711-11 Email: info@femto.de www.femto.de Specifications are subject to change without notice. Information provided herein is believed to be accurate and reliable. However, no responsibility is assumed by FEMTO Messtechnik GmbH for its use, nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of FEMTO Messtechnik GmbH. Product names mentioned may also be trademarks used here for identification purposes only.

© by FEMTO Messtechnik GmbH · Printed in Germany

F E M T O